



GaAs PHEMT MMIC LOW NOISE AMPLIFIER w/ BYPASS MODE, 700 - 1000 MHz

Typical Applications

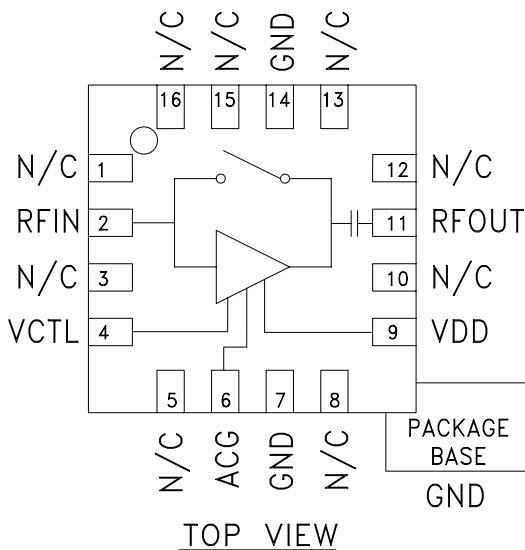
The HMC373LP3 / HMC373LP3E is ideal for basestation receivers:

- GSM, GPRS & EDGE
- CDMA & W-CDMA
- Private Land Mobile Radio

Features

- Noise Figure: 0.9 dB
- Output IP3: +35 dBm
- Gain: 14 dB
- Low Loss LNA Bypass Path
- Single Supply: +5V @ 90 mA
- 50 Ohm Matched Output

Functional Diagram



General Description

The HMC373LP3 / HMC373LP3E are versatile, high dynamic range GaAs MMIC Low Noise Amplifiers that integrate a low loss LNA bypass mode on the IC. The amplifier is ideal for GSM & CDMA cellular basestation front-end receivers operating between 700 and 1000 MHz and provides 0.9 dB noise figure, 14 dB of gain and +35 dBm IP3 from a single supply of +5V @ 90 mA. Input and output return losses are 28 and 12 dB respectively with the LNA requiring minimal external components to optimize the RF input match, RF ground and DC bias. By presenting an open or short circuit to a single control line, the LNA can be switched into a low 2.0 dB loss bypass mode reducing the current consumption to 10 μ A. For applications which require improved noise figure, please see the HMC668LP3(E).

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{dd} = +5\text{V}$

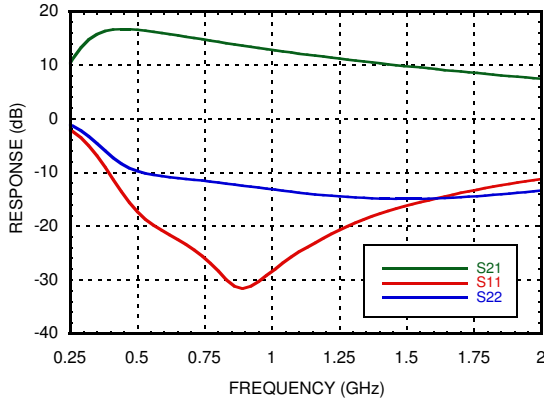
| Parameter | LNA Mode | | | LNA Mode | | | Bypass Mode | | | Units |
|--|-----------|-------|-------|------------|-------|-------|-------------|-------|-------|-----------------------|
| | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. | |
| Frequency Range | 810 - 960 | | | 700 - 1000 | | | 700 - 1000 | | | MHz |
| Gain | 11.5 | 13.5 | | 10.5 | 14 | | -2.8 | -2.0 | | dB |
| Gain Variation Over Temperature | | 0.008 | 0.015 | | 0.008 | 0.015 | | 0.002 | 0.004 | dB / $^\circ\text{C}$ |
| Noise Figure | | 0.9 | 1.3 | | 1.0 | 1.4 | | | | dB |
| Input Return Loss | | 28 | | | 25 | | | 30 | | dB |
| Output Return Loss | | 12 | | | 11 | | | 25 | | dB |
| Reverse Isolation | | 20 | | | 19 | | | | | dB |
| Power for 1dB Compression (P1dB)* | 18 | 21 | | 17 | 20 | | | 30 | | dBm |
| Saturated Output Power (P _{sat}) | | 22.5 | | | 22 | | | | | dBm |
| Third Order Intercept (IP3)* (-20 dBm Input Power per tone, 1 MHz tone spacing) | | 35.5 | | | 35 | | | 50 | | dBm |
| Supply Current (I _{dd}) | | 90 | | | 90 | | | 0.01 | | mA |

* P1dB and IP3 for LNA Mode are referenced to RFOUT while P1dB and IP3 for Bypass Mode are referenced to RFIN.

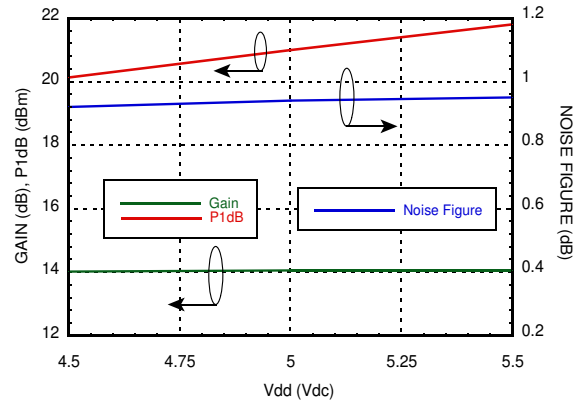


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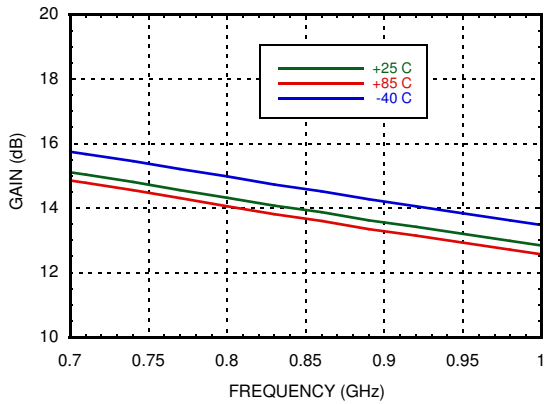
LNA Broadband Gain & Return Loss



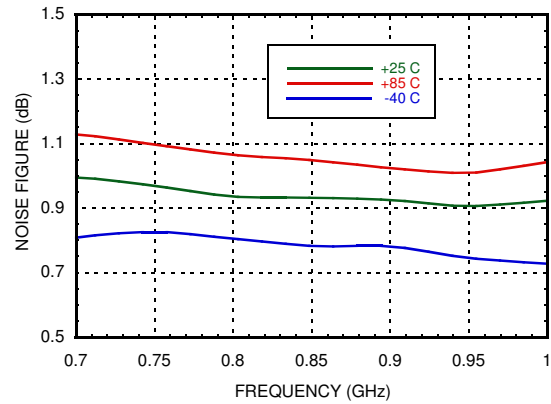
LNA – Gain, Noise Figure & Power vs. Supply Voltage @ 850 MHz



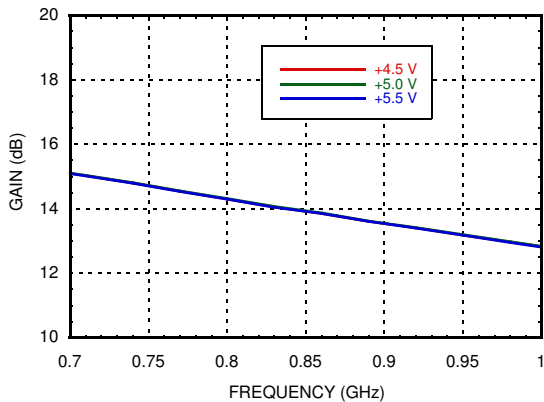
LNA Gain vs. Temperature



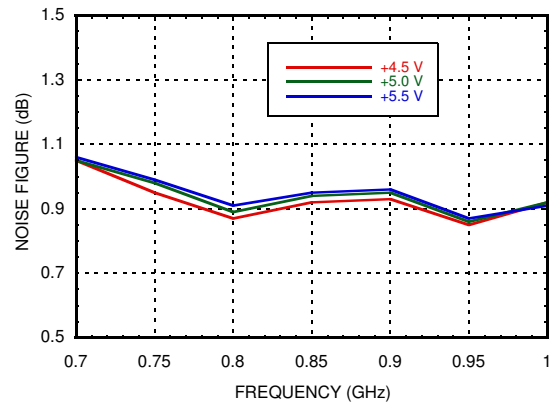
LNA Noise Figure vs. Temperature



LNA Gain vs. Vdd



LNA Noise Figure vs. Vdd

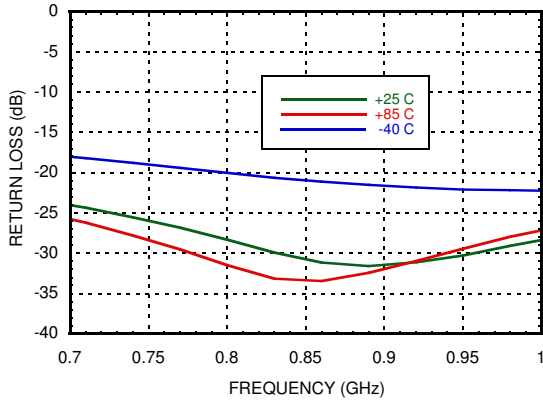




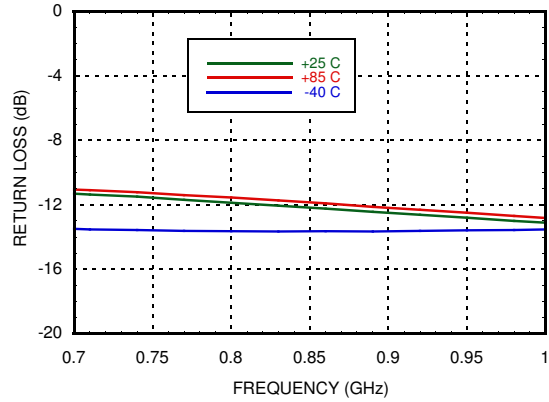
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AMPLIFIERS - LOW NOISE - SMT

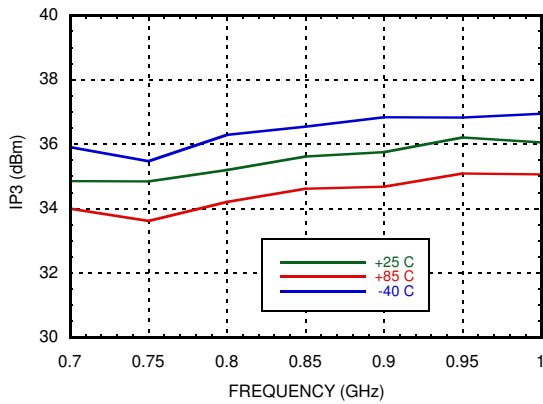
LNA Input Return Loss vs. Temperature



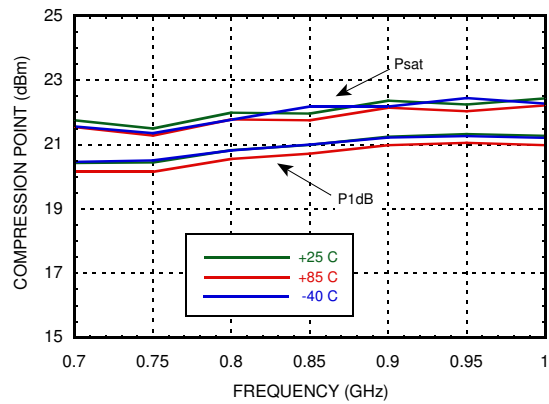
LNA Output Return Loss vs. Temperature



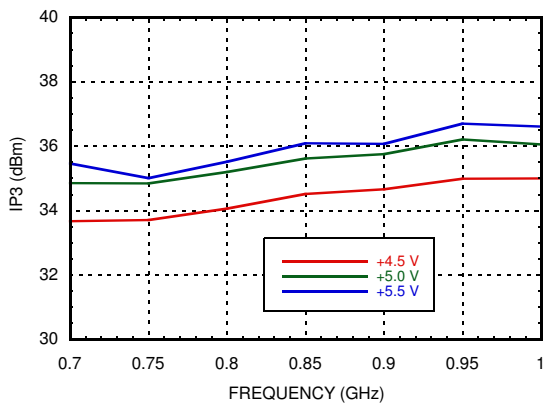
LNA Output IP3 vs. Temperature



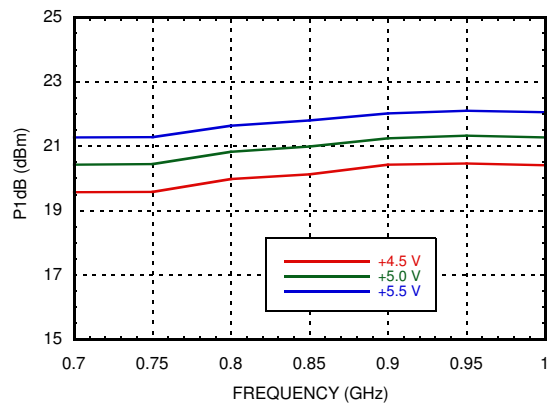
LNA P1dB & Psat vs. Temperature



LNA Output IP3 vs. Vdd



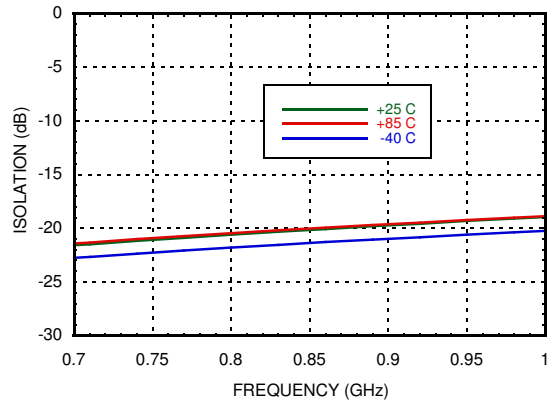
LNA P1dB vs. Vdd



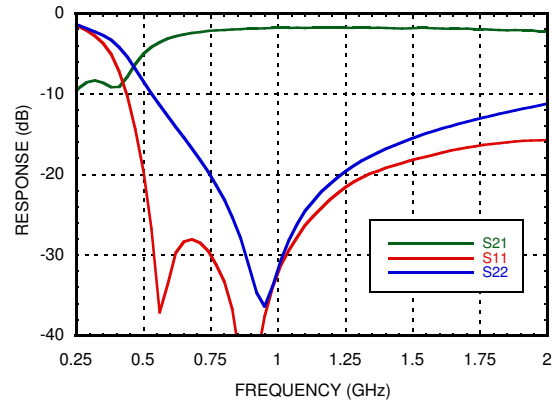


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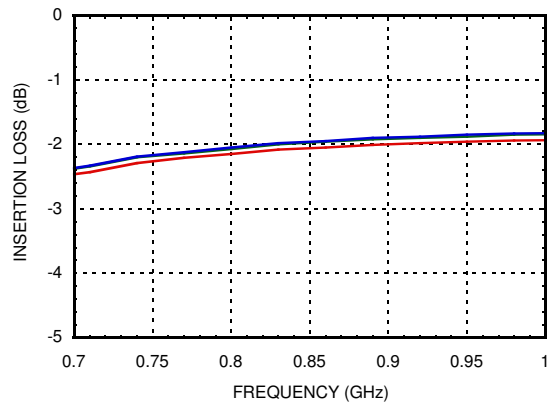
LNA Reverse Isolation vs. Temperature



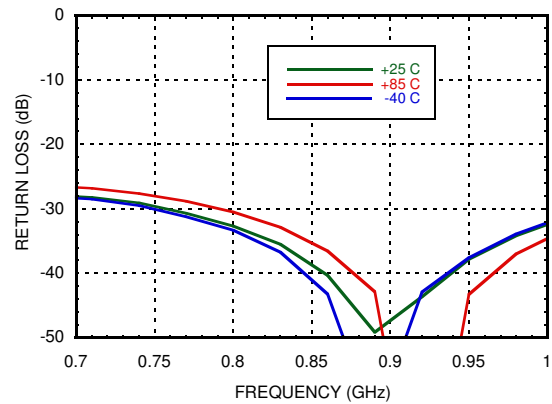
Bypass Mode Broadband Insertion Loss & Return Loss



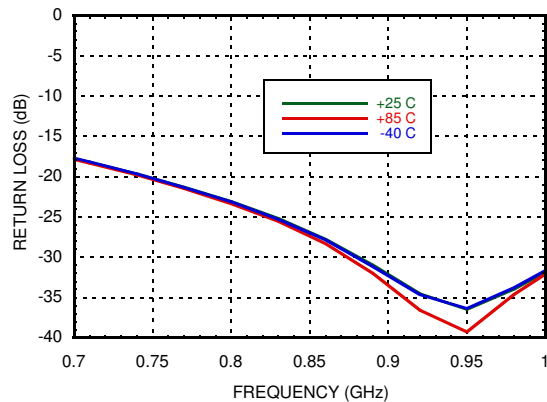
Bypass Mode Insertion Loss vs. Temperature



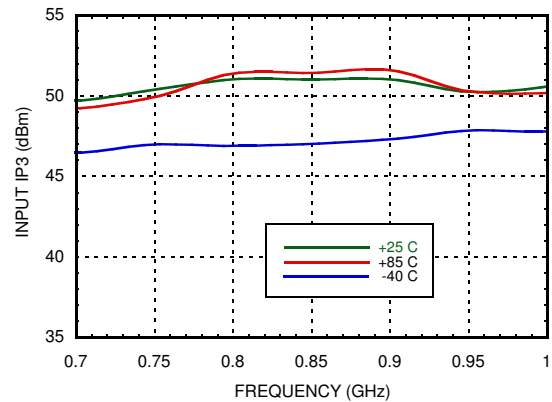
Bypass Mode Input Return Loss vs. Temperature



Bypass Mode Output Return Loss vs. Temperature



Bypass Mode Input IP3 vs. Temperature





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Absolute Maximum Ratings

| | |
|---|---|
| Drain Bias Voltage (Vdd) | +8.0 Vdc |
| RF Input Power (RFIN) (Vdd = +5.0 Vdc) | LNA Mode +15 dBm Bypass Mode +30 dBm |
| Channel Temperature | 150 °C |
| Continuous Pdiss (T = 85 °C) (derate 13.5 mW/°C above 85 °C) | 0.878 W |
| Thermal Resistance (channel to ground paddle) | 74.1 °C/W |
| Storage Temperature | -65 to +150° C |
| Operating Temperature | -40 to +85° C |

Typical Supply Current vs. Vdd

| Vdd (Vdc) | Idd (mA) |
|-----------|----------|
| +4.5 | 87 |
| +5.0 | 90 |
| +5.5 | 93 |

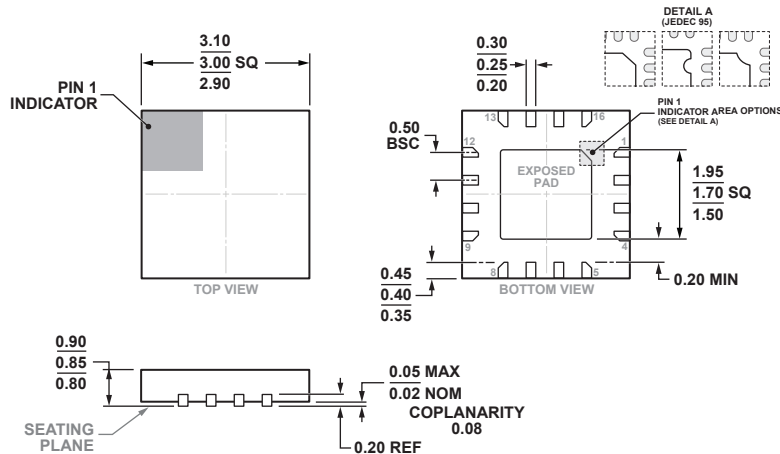
Truth Table

| | |
|-------------|----------------------------------|
| LNA Mode | Vctl= Short Circuit to DC Ground |
| Bypass Mode | Vctl= Open Circuit |



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



COMPLIANT WITH JEDEC STANDARDS MO-220-VEED-4.

16-Lead Lead Frame Chip Scale Package [LFCSP]
3 mm x 3 mm Body and 0.85 mm Package Height
(HCP-16-1)

Dimensions shown in millimeters

Package Information

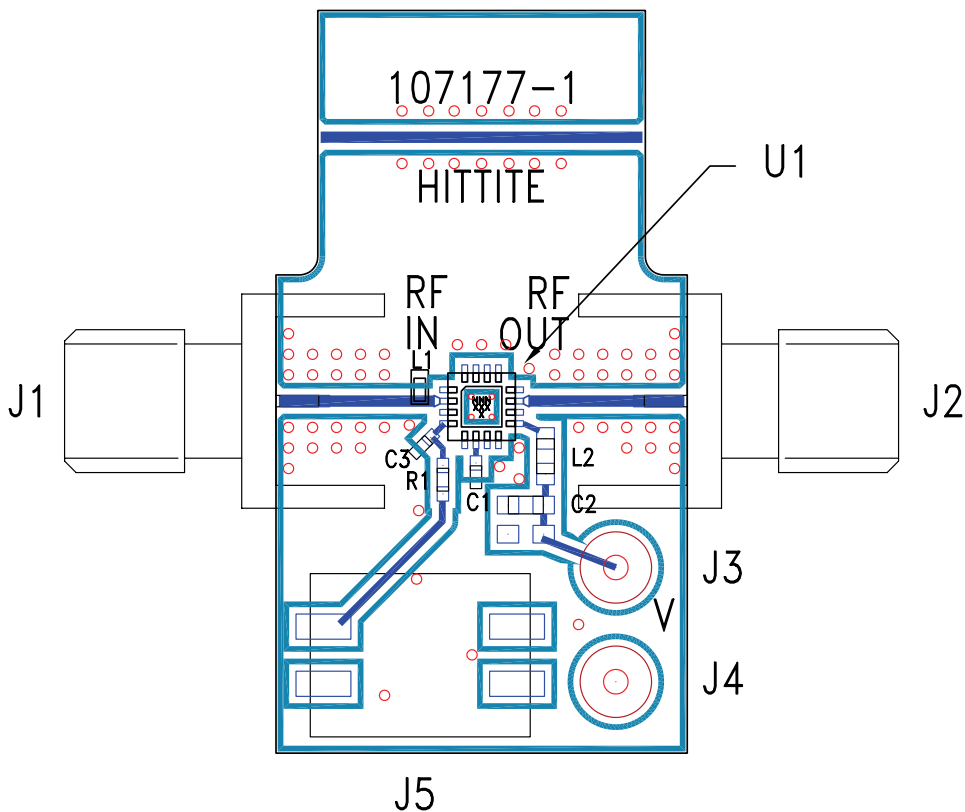
| Part Number | Package Body Material | Lead Finish | MSL Rating ^[1] | Package Marking ^[2] |
|--------------|--|---------------|---------------------------|--------------------------------|
| HMC373LP3E | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL3 | 373 XXXX |
| HMC373LP3ETR | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL3 | 373 XXXX |

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX

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Evaluation PCB



List of Materials for Evaluation PCB 107220 [1]

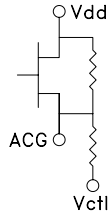
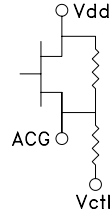

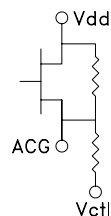
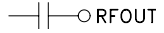
| Item | Description |
|---------|----------------------------------|
| J1 - J2 | PCB Mount SMA RF Connector |
| J3 - J4 | DC Pin |
| J5 | 2 Pos DIP Switch |
| C1 | 10000 pF Capacitor, 0402 Pkg. |
| C2 | 10000 pF Capacitor, 0603 Pkg. |
| C3 | 1000 pF Capacitor, 0402 Pkg. |
| L1 | 19 nH Inductor, 0402 Pkg. |
| L2 | 18 nH Inductor, 0603 Pkg. |
| R1 | 2 Ohm Resistor, 0402 Pkg. |
| U1 | HMC373LP3 / HMC373LP3E Amplifier |
| PCB [2] | 107177 Evaluation Board |

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Analog Devices upon request.

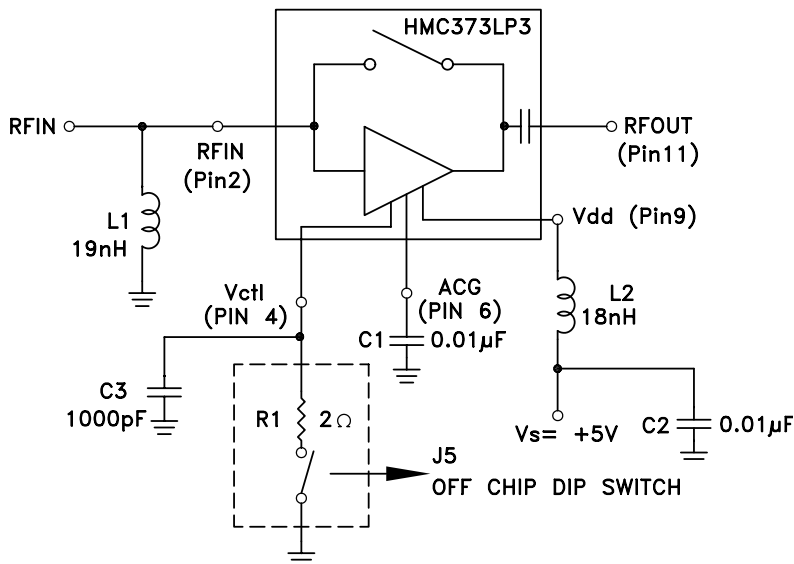

**GaAs PHEMT MMIC LOW NOISE
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Pin Descriptions

| Pin Number | Function | Description | Interface Schematic |
|--------------------------------|----------|---|---|
| 1, 3, 5, 8, 10, 12, 13, 15, 16 | N/C | No connection necessary. These pins may be connected to RF/DC ground. | |
| 2 | RFIN | This pin is matched to 50 Ohms with a 19 nH inductor to ground. See Application Circuit. | RFIN ○ — |
| 4 | Vctl | DC ground return. LNA is in high gain mode when a short circuit is introduced to this pin through an external switch. LNA is in bypass mode when open circuit is introduced |  |
| 6 | ACG | An external capacitor of 0.01μF to ground is required for low frequency bypassing. See Application Circuit for further details. |  |
| 7, 14 | GND | These pins must be connected to RF/DC ground. |  |
| 9 | Vdd | Power supply voltage. Choke inductor and bypass capacitor are required. See application circuit. |  |
| 11 | RFOUT | This pin is AC coupled and matched to 50 Ohms. |  |

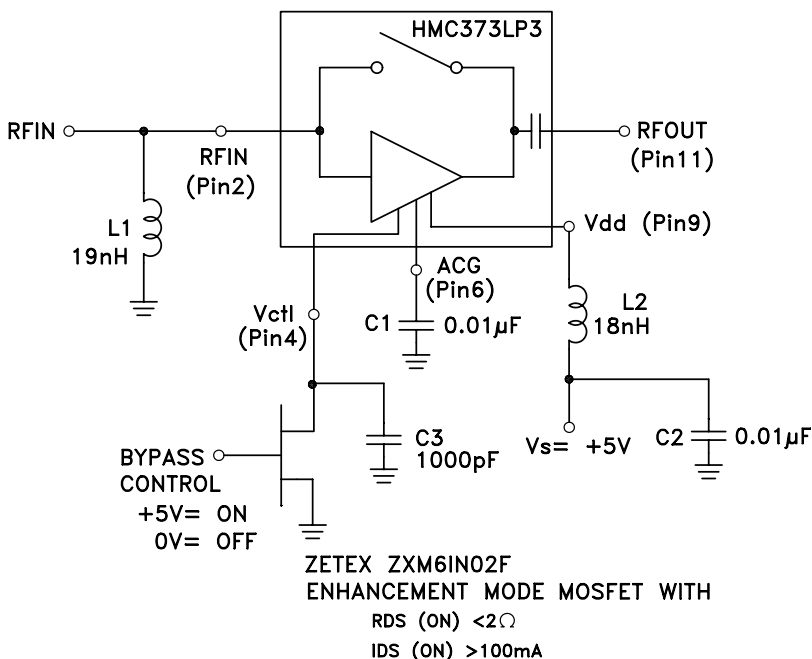


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Evaluation Board Circuit



Application Circuit



Note 1: Choose value of capacitor C1 for low frequency bypassing. A 0.01 μF $\pm 10\%$ capacitor is recommended.

Note 2: Pin 4 (Vctl) is the DC ground return for the circuit. The LNA is in the high gain mode when a short circuit is introduced to this pin through an external switch. The LNA is in bypass mode when an open circuit is introduced. For the data presented, switching is done through a two position DIP switch (J5) in series with a 2 Ohm resistor (to account for the R_{on} of an electrical switch).

Note 3: L1, L2 and C1 should be located as close to pins as possible.

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JONHON

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ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



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